

# 74LVCH16245A-Q100 74LVC16245A-Q100;

16-bit bus transceiver with direction pin; 5 V tolerant; 3-state Product data sheet

## 1. General description

The 74LVC16245A-Q100; 74LVCH16245A-Q100 is a 16-bit transceiver with 3-state outputs. The device can be used as two 8-bit transceivers or one 16-bit transceiver. The device features two output enables (10E and 20E) each controlling eight outputs, and two send/receive (1DIR and 2DIR) inputs for direction control. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Overvoltage tolerant inputs to 5.5 V
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power dissipation
- MULTIBYTE flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- · Direct interface with TTL levels
- All data inputs have bus hold (74LVCH16245A-Q100 only)
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Complies with JEDEC standard:
  - JESD8-7A (1.65 V to 1.95 V)
  - JESD8-5A (2.3 V to 2.7 V)
  - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

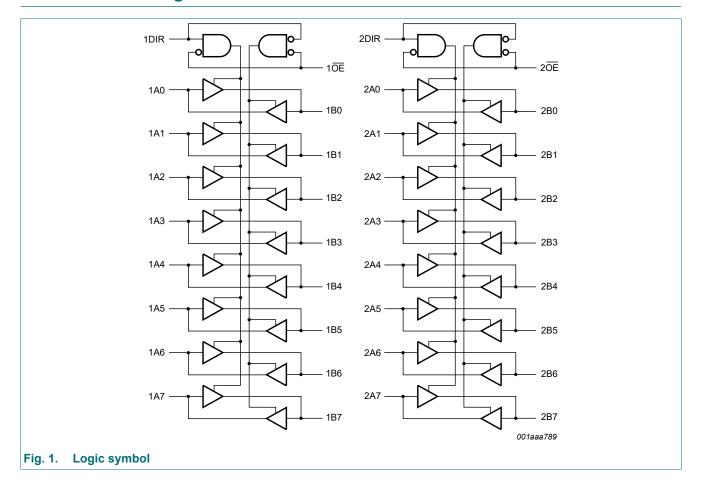


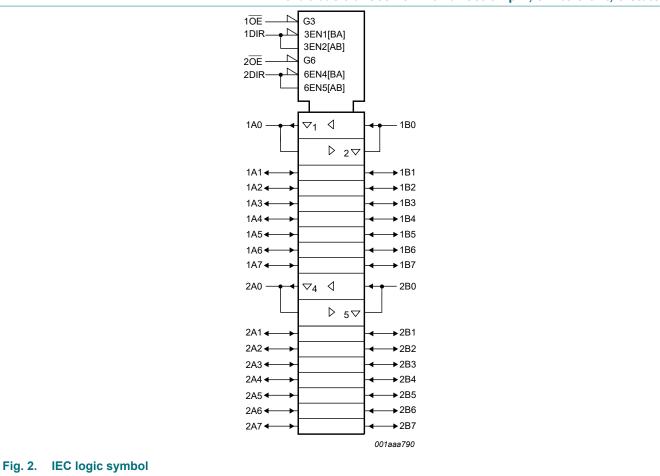
# 3. Ordering information

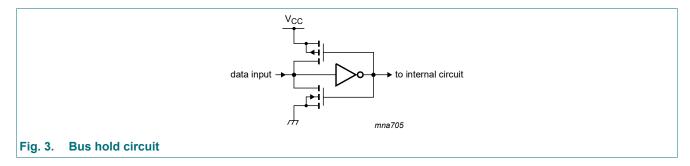
**Table 1. Ordering information** 

Type number	Temperature range	Package		
		Name	Description	Version
74LVC16245ADGG-Q100 74LVCH16245ADGG-Q100	-40 °C to +125 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1
74LVC16245ADGV-Q100 74LVCH16245ADGV-Q100	-40 °C to +125 °C	TVSOP48	plastic thin shrink small outline package; 48 leads; body width 4.4 mm; lead pitch 0.4 mm	SOT480-1

## 4. Functional diagram

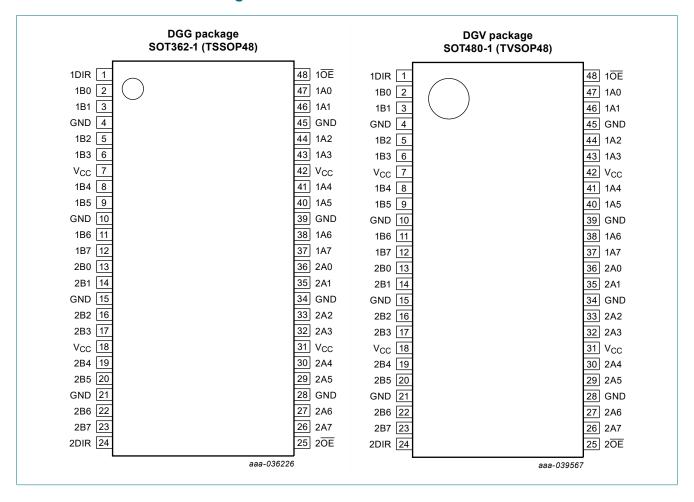






## 5. Pinning information

#### 5.1. Pinning



## 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1DIR, 2DIR	1, 24	direction control input
1B0, 1B1, 1B2, 1B3, 1B4, 1B5, 1B6, 1B7	2, 3, 5, 6, 8, 9, 11, 12	data input/output
2B0, 2B1, 2B2, 2B3, 2B4, 2B5, 2B6, 2B7	13, 14, 16, 17, 19, 20, 22, 23	data input/output
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
Vcc	7, 18, 31, 42	supply voltage
10E, 20E	48, 25	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3, 1A4, 1A5, 1A6, 1A7	47, 46, 44, 43, 41, 40, 38, 37	data input/output
2A0, 2A1, 2A2, 2A3, 2A4, 2A5, 2A6, 2A7	36, 35, 33, 32, 30, 29, 27, 26	data input/output

## 6. Functional description

#### **Table 3. Function table**

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$ 

·		Outputs		
ŌE nDIR		nAn	nBn	
L	L	nAn = nBn	inputs	
L	Н	inputs	nBn = nAn	
Н	X	Z	Z	

## 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	-	±50	mA
Vo	output voltage	output HIGH or LOW [2]	-0.5	V <sub>CC</sub> + 0.5	V
		output 3-state [2]	-0.5	+6.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [3]	-	500	mW

<sup>[1]</sup> The minimum input voltage ratings may be exceeded if the input current ratings are observed.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	-	3.6	V
		functional	1.2	-	3.6	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	output HIGH or LOW	0	-	V <sub>CC</sub>	V
		output 3-state	0	-	5.5	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.2 V to 2.7 V	0	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	-	10	ns/V

<sup>[2]</sup> The output voltage ratings may be exceeded if the output current ratings are observed.

<sup>[3]</sup> For SOT362-1 (TSSOP48) packages: P<sub>tot</sub> derates linearly with 12.2 mW/K above 109 °C. For SOT480-1 (TVSOP48) packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

## 9. Static characteristics

**Table 6. Static characteristics** 

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to +125 °C		Unit
				Min	Typ [1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 1.2 V		1.08	-	-	1.08	-	V
	voltage	V <sub>CC</sub> = 1.65 V to 1.95 V		0.65V <sub>CC</sub>	-	-	0.65V <sub>CC</sub>	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.7	-	-	1.7	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V		2.0	-	-	2.0	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 1.2 V		-	-	0.12	-	0.12	V
	voltage	V <sub>CC</sub> = 1.65 V to 1.95 V		-	-	0.35V <sub>CC</sub>	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	-	0.7	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V		-	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>							
	voltage	I <sub>O</sub> = -100 μA; V <sub>CC</sub> = 1.65 V to 3.6 V		V <sub>CC</sub> - 0.2	-	-	V <sub>CC</sub> - 0.3	-	V
		$I_O = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$		1.2	-	-	1.05	-	V
		$I_O = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.8	-	-	1.65	-	V
		$I_{O}$ = -12 mA; $V_{CC}$ = 2.7 V		2.2	-	-	2.05	-	V
		$I_O = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.4	-	-	2.25	-	V
		$I_{O}$ = -24 mA; $V_{CC}$ = 3.0 V		2.2	-	-	2.0	-	V
V <sub>OL</sub>	LOW-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>							
	voltage	I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 3.6 V		-	-	0.2	-	0.3	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V		-	-	0.45	-	0.65	V
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.6	-	0.8	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V		-	-	0.4	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	0.55	-	0.8	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 3.6 V	[2]	-	±0.1	±5	-	±20	μΑ
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = 5.5$ V or GND; $V_{CC} = 3.6$ V	[2][3]	-	±0.1	±5	-	±20	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 5.5 \text{ V}$ ; $V_{CC} = 0.0 \text{ V}$		-	±0.1	±10	-	±20	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 3.6 \text{ V}$		-	0.1	20	-	80	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 2.7 \text{ V}$ to 3.6 V		-	5	500	-	5000	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; V <sub>I</sub> = GND to $V_{CC}$		-	5.0	-	-	-	pF
C <sub>I/O</sub>	input/output capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_{I}$ = GND to $V_{CC}$		-	10	-	-	-	pF
I <sub>BHL</sub>	bus hold LOW	V <sub>CC</sub> = 1.65; V <sub>I</sub> = 0.58 V	[4][5]	10	-	-	10	-	μΑ
	current	V <sub>CC</sub> = 2.3; V <sub>I</sub> = 0.7 V		30	-	-	25	-	μΑ
		V <sub>CC</sub> = 3.0; V <sub>I</sub> = 0.8 V		75	-	-	60	-	μΑ

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
I <sub>BHH</sub>	bus hold HIGH	$V_{CC} = 1.65; V_I = 1.07 V$ [4][5]	-10	-	-	-10	-	μΑ
	current	$V_{CC} = 2.3; V_I = 1.7 V$	-30	-	-	-25	-	μΑ
		V <sub>CC</sub> = 3.0; V <sub>I</sub> = 2.0 V	-75	-	-	-60	-	μΑ
I <sub>BHLO</sub>	bus hold LOW	V <sub>CC</sub> = 1.95 V [4][6]	200	-	-	200	-	μA
	overdrive current	V <sub>CC</sub> = 2.7 V	300	-	-	300	-	μΑ
		V <sub>CC</sub> = 3.6 V	500	-	-	500	-	μA
I <sub>BHHO</sub>		V <sub>CC</sub> = 1.95 V [4][6]	-200	-	-	-200	-	μΑ
	overdrive current	V <sub>CC</sub> = 2.7 V	-300	-	-	-300	-	μΑ
		V <sub>CC</sub> = 3.6 V	-500	-	-	-500	-	μA

- [1] All typical values are measured at  $V_{CC}$  = 3.3 V (unless stated otherwise) and  $T_{amb}$  = 25 °C.
- [2] The bus hold circuit is switched off when  $V_I > V_{CC}$  allowing 5.5 V on the input terminal.
- [3] For I/O ports the parameter I<sub>OZ</sub> includes the input leakage current.
- [4] Valid for data inputs of bus hold parts only (74LVCH16245A-Q100). Note that control inputs do not have a bus hold circuit.
- The specified sustaining current at the data input holds the input below the specified V<sub>I</sub> level.
- [6] The specified overdrive current at the data input forces the data input to the opposite input state.

## 10. Dynamic characteristics

**Table 7. Dynamic characteristics** 

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 6.

Symbol	Parameter	Conditions	-4	0 °C to +85	°C	-40 °C to +125 °C		
			Min	Typ [1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	nAn to nBn; nBn to nAn; see Fig. 4	2]					
		V <sub>CC</sub> = 1.2 V	-	13.0	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.5	5.2	12.2	1.5	13.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	2.8	6.0	1.0	6.7	ns
		V <sub>CC</sub> = 2.7 V	1.0	2.7	4.7	1.0	6.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.4	4.5	1.0	6.0	ns
t <sub>en</sub>	enable time	nOE to nAn, nBn; see Fig. 5	2]					
		V <sub>CC</sub> = 1.2 V	-	15.0	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.5	5.9	15.0	1.5	16.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	3.3	7.9	1.0	8.8	ns
		V <sub>CC</sub> = 2.7 V	1.5	3.5	6.7	1.5	8.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.7	5.5	1.0	7.0	ns
t <sub>dis</sub>	disable time	nOE to nAn, nBn; see Fig. 5	2]					
		V <sub>CC</sub> = 1.2 V	-	11.0	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	4.9	13.1	1.0	14.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.5	2.7	7.1	0.5	7.9	ns
		V <sub>CC</sub> = 2.7 V	1.5	3.4	6.6	1.5	8.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	3.3	5.6	1.5	7.0	ns

Symbol	Parameter Conditions		-40	°C to +85	°C	-40 °C to	Unit	
			Min	Typ [1]	Max	Min	Max	
C <sub>PD</sub>	power	per input; $V_I = GND$ to $V_{CC}$ [3]						
	dissipation capacitance	V <sub>CC</sub> = 1.65 V to 1.95 V	-	11.5	-	-	-	pF
	capacitance	V <sub>CC</sub> = 2.3 V to 2.7 V	-	15.2	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	18.5	-	-	-	pF

- [1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

ten is the same as tPZL and tPZH.

 $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz; f<sub>o</sub> = output frequency in MHz

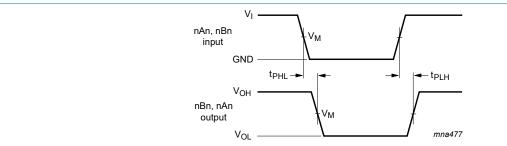
C<sub>L</sub> = output load capacitance in pF

V<sub>CC</sub> = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

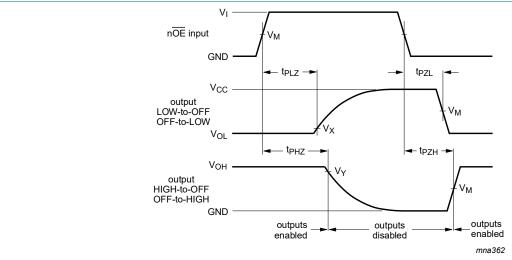
#### 10.1. Waveforms and test circuit



Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig. 4. The input (nAn, nBn) to output (nBn, nAn) propagation delays



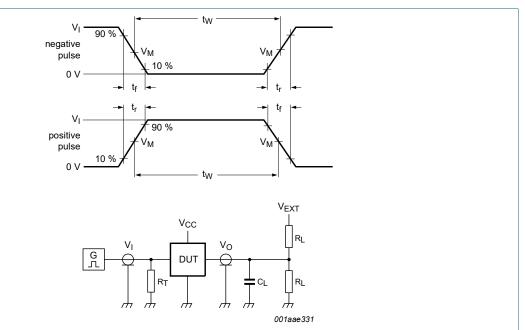
Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Fig. 5. 3-state enable and disable times

**Table 8. Measurement points** 

Supply voltage	Input	Input		Output			
V <sub>CC</sub>	V <sub>M</sub>	VI	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
1.2 V	0.5V <sub>CC</sub>	V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V		
1.65 V to 1.95 V	0.5V <sub>CC</sub>	V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V		
2.3 V to 2.7 V	0.5V <sub>CC</sub>	V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V		
2.7 V	1.5 V	2.7 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V		
3.0 V to 3.6 V	1.5 V	2.7 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V		



Test data is given in Table 9.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $V_{\mathsf{EXT}}$  = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input	Load		V <sub>EXT</sub>			
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>
1.2 V	V <sub>CC</sub>	≤ 2 ns	30 pF	1 kΩ	open	2V <sub>CC</sub>	GND
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2 ns	30 pF	1 kΩ	open	2V <sub>CC</sub>	GND
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2 ns	30 pF	500 Ω	open	2V <sub>CC</sub>	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2V <sub>CC</sub>	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2V <sub>CC</sub>	GND

## 11. Package outline

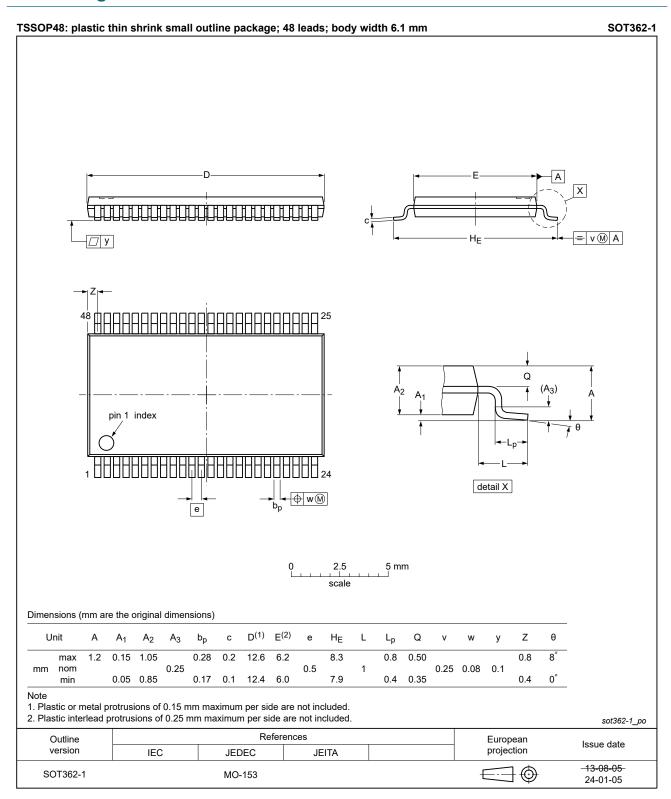


Fig. 7. Package outline SOT362-1 (TSSOP48)

TVSOP48: plastic thin shrink small outline package; 48 leads; body width 4.4 mm; lead pitch 0.4 mm

SOT480-1

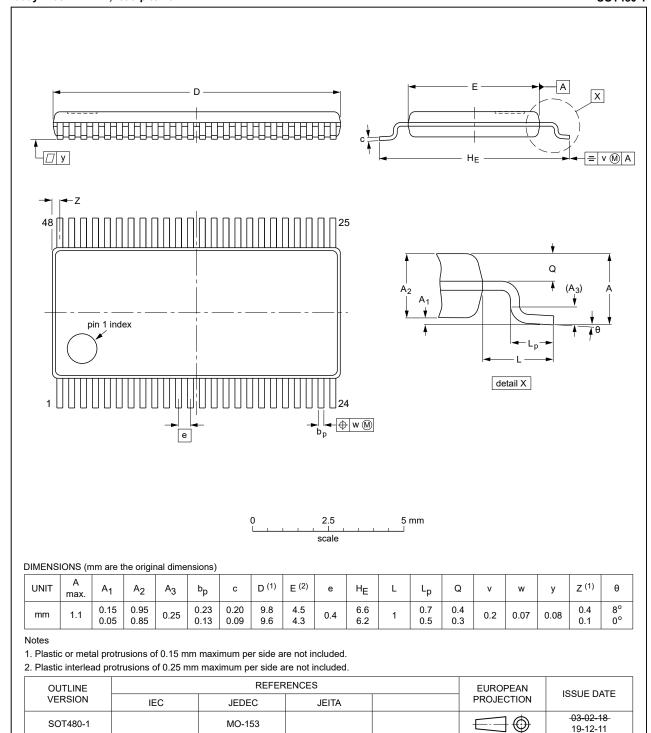


Fig. 8. Package outline SOT480-1 (TVSOP48)

## 12. Abbreviations

#### **Table 10. Abbreviations**

Acronym	Description			
CDM	Charged Device Model			
CMOS	mplementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
TTL	Transistor-Transistor Logic			

# 13. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC_LVCH16245A_Q100 v.5	20240423	Product data sheet	-	74LVC_LVCH16245A_Q100 v.4		
Modifications:	Fig. 7: Updated package outline drawing SOT362-1 (TSSOP48).					
74LVC_LVCH16245A_Q100 v.4	20230801	Product data sheet	-	74LVC_LVCH16245A_Q100 v.3		
Modifications:	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.					
74LVC_LVCH16245A_Q100 v.3	20210924	Product data sheet	-	74LVC_LVCH16245A_Q100 v.2		
Modifications:	<ul> <li><u>Section 1</u> and <u>Section 2</u> updated.</li> <li><u>Table 4</u>: Derating values for P<sub>tot</sub> total power dissipation updated.</li> <li><u>Fig. 8</u>: Package outline drawing SOT480-1 (TVSOP48) updated.</li> </ul>					
74LVC_LVCH16245A_Q100 v.2	20190104	Product data sheet	-	74LVC_LVCH16245A_Q100 v.1		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74LVC16245AEV-Q100 and 74LVCH16245AEV-Q100 (SOT702-1) removed.</li> <li>Type numbers 74LVC16245ADGV-Q100 and 74LVCH16245ADGV-Q100 (SOT480-1) added.</li> <li>Package outline drawing Fig. 7 (TSSOP48) updated.</li> </ul>					
74LVC_LVCH16245A_Q100 v.1	20121120	Product data sheet	-	-		

## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or [1] completing a design.
- The term 'short data sheet' is explained in section "Definitions".
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